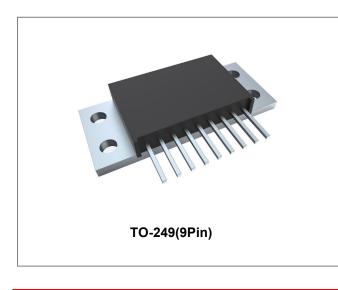


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152CMQ030 SCHOTTKY RECTIFIER



ISOLATED BASE

ANODE COMMON ANODE CATHODE (4-6) (7-9)

Features

- 150 °C T_J operation
- **Isolated heatsink**
- Multiple leads per terminal for high frequency, high current PC board mounting
- Low profile, high current package
- Center tap module
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for • enhanced mechanical strength and moisture resistance
- High frequency operation •
- Guard ring for enhanced ruggedness and long term reliability ٠
- Baseplate: Nickel plated; Terminals: Nickel plated •
- This is a Pb Free Device •
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**

Maximum Ratings:

(1 - 3)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	30	v
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc =85°C, rectangular wave form	75(Per Leg) 150(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	1200	А
Non-Repetitive Avalanche Energy (Peg Leg)	Eas	TJ=25℃,I _{AS} =15A,L=0.6mH	68	mJ
Repetitive Avalanche Current(Peg Leg)	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max.V _A =1.5×V _R typical	15	A

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Schematic & Pin Configuration



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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Peg Leg)*	V_{F1}	@ 75A, Pulse, T」 = 25 °C @ 150A, Pulse, T」 = 25 °C	0.50 -	0.55 0.69	V
	V _{F2}	@ 75A, Pulse, T」 = 125 °C @ 150A, Pulse, T」 = 125 °C	0.40	0.47 0.66	V
Reverse Current(Peg Leg)*	I _{R1}	$@V_R = rated V_{R,T_J} = 25 \ ^{\circ}C$	0.2	5	mA
	I _{R2}	$@V_R$ = rated V_R , T_J = 125 °C	160	280	mA
Junction Capacitance(Peg Leg)	Ст	$@V_R = 5V, T_C = 25 \circ C$ $f_{SIG} = 1MHz$	2900	3700	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (Per Leg)	Rejc	DC operation	1.0	°C/W
Typical Thermal Resistance Junction to Case (Per Package)	R _{0JC}	DC operation	0.50	°C/W
Typical Thermal Resistance, case to Heat Sink	R _{0cs}	Mounting surface, smooth and greased	0.10	°C/W
Mounting Torque	Тм	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	56	g
Case Style	TO-249(9 pin)			

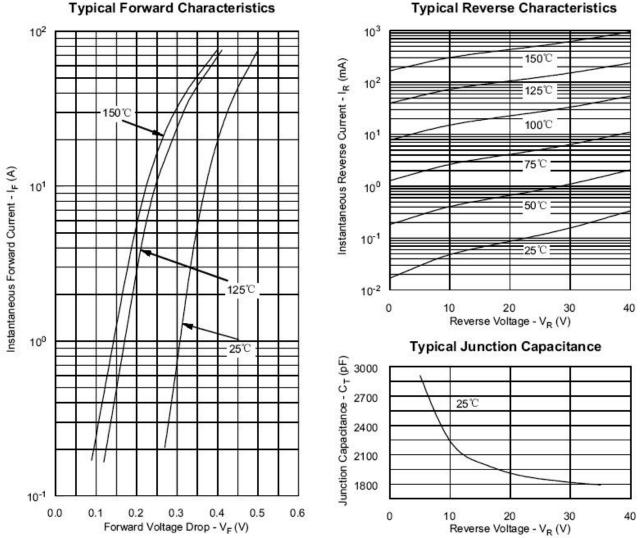
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RoHS

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Ratings and Characteristics Curves



Typical Reverse Characteristics

Ordering Information

Device	Package	Shipping
152CMQ030	TO-249(Pb-Free)	24pcs/ box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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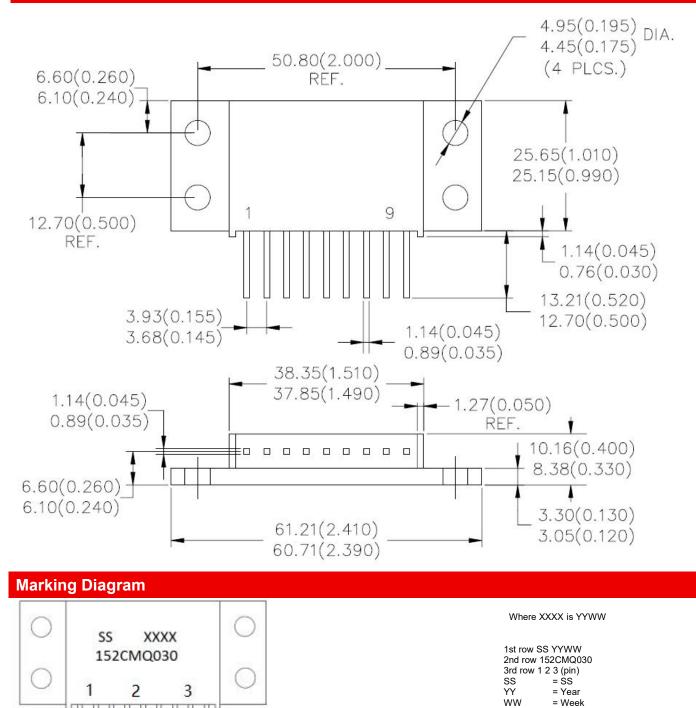
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RoHS 🗭

Mechanical Dimensions TO-249(9pin) (Inches/Millimeters)



Cautions: Molding resin Epoxy resin UL:94V-0

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